IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re	U.S. Patent Application of)
MAT	SUOKA et al.)
Appli	ication Number: To Be Assigned)
Filed	: Concurrently Herewith)
For:	SEMICONDUCTOR MEMORY CELL AND METHOD OF FORMING SAME)
Атто	DRNEY DOCKET NO. NITT.0204)

Honorable Assistant Commissioner for Patents Washington, D.C. 20231

INFORMATION DISCLOSURE STATEMENT

The above-referenced application is a Continuation of U.S. Serial No. 10/307,373 filed December 2, 2002.

It is understood that the listed references will be considered in the examination of the application and that no separate copies of the same prior art are required to be provided since they were previously cited or transmitted in the foregoing prior application, pursuant to 37 CFR § 1.98(d). Form(s) PTO 1449 is enclosed listing references cited by the Examining Attorney and submitted by applicant in the prior applications.

This Information Disclosure Statement is submitted with the above-captioned U.S. Continuation application. Accordingly, no fee is due or payable at this time.

The Examiner is requested to acknowledge consideration of the information provided in this paper in accordance with prescribed procedures.

Please charge any additional fees or credit any overpayments in connection with this paper to Deposit Account No. 08-1480.

Respectfully submitted,

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Form PTO 1449	ATTY. DOCKET NUMBER NITT.0204	Serial Number To Be Assigned
U.S. Department of Commerce Patent and Trademark Office	APPLICANT MATSUOKA et al	•
Information Disclosure Statement by Applicant	FILING DATE Concurrently Herewith	GROUP

U.S. Patent Documents

Examiner		DOCUMENT	DATE	Name	CLASS	SUBC	FILING DATE
Initial		Number				LASS	1 100 0 0 111 0
	Х	6,087,674	7/11/00	Ovshinsky et al.			04/20/98
	Х	5,920,788	7/06/99	Reinberg			12/16/97
	X	6,429,449 B1	8/06/02	Gonzalez et al.			5/12/00
	X	6,437,383 B1	8/20/02	Xu et al.			12/21/00
	XX	4,845,533	7/4/89	Pryor et al.			11/26/86
	XX	5,032,538	7/16/91	Bozler et al.			7/7/87

Foreign Patent Documents

Examiner	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLASS	Sub-	Translation	
Initial					CLASS	YES	No
	1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 -						
			<u> </u>				

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

:	Х	Stefan LAI, Tyler LOWREY, "OUM - A 180 nm Nonvolatile Memory Cell Element Technology For Stand Alone and Embedded Applications", 2001, IEDM Technical Digest Paper, pp. 36.5
		<u> </u>

X = Filed by Applicant in Parent XX = Cited by Examiner in Parent PTO1449